



PNP MEDIUM POWER TRANSISTORS IN SOT223

Features

- BV_{CEO} > -45V, -60V & -80V
- I_C = -1A High Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < -500mV @ -0.5A
- Gain Groups 10 and 16
- Complementary NPN Types: BCP54, 55 and 56
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.112 grams (Approximate)

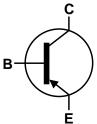
Applications

- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages

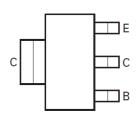








Device Symbol



Top View Pin-Out

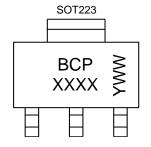
Ordering Information (Notes 4 & 5)

| Product | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel | |
|------------|------------|--|--------------------|-----------------|-------------------|--|
| BCP51TA | AEC-Q101 | BCP 51 | 7 | 12 | 1,000 | |
| BCP5110TA | AEC-Q101 | BCP 5110 | 7 | 12 | 1,000 | |
| BCP5116TA | AEC-Q101 | BCP 5116 | 7 | 12 | 1,000 | |
| BCP5116TC | AEC-Q101 | BCP 5116 | 13 | 12 | 4,000 | |
| BCP52TA | AEC-Q101 | BCP 52 | 7 | 12 | 1,000 | |
| BCP5210TA | AEC-Q101 | BCP 5210 | 7 | 12 | 1,000 | |
| BCP5216TA | AEC-Q101 | BCP 5216 | 7 | 12 | 1,000 | |
| BCP53TA | AEC-Q101 | BCP 53 | 7 | 12 | 1,000 | |
| BCP53QTA | Automotive | BCP 53 | 7 | 12 | 1,000 | |
| BCP5310TA | AEC-Q101 | BCP 5310 | 7 | 12 | 1,000 | |
| BCP5316TA | AEC-Q101 | BCP 5316 | 7 | 12 | 1,000 | |
| BCP5316QTA | Automotive | Refer to http://diodes.com/datasheets/BCP5316Q.pdf | | | | |
| BCP5316TC | AEC-Q101 | BCP 5316 | 13 | 12 | 4,000 | |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



BCP = Product Type Marking Code, Line 1 XXXX = Product Type Marking Code, Line 2 as follows:

BCP51 = 51 BCP52 = 52 BCP53 = 53 BCP5110 = 5110 BCP5210 = 5210 BCP5310 = 5310 BCP5116 = 5116 BCP5216 = 5216 BCP5316 = 5316

YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)

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Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | BCP51 | BCP52 | BCP53 | Unit |
|------------------------------|------------------|-------|-------|-------|---------|
| Collector-Base Voltage | V _{CBO} | -45 | -60 | -100 | V |
| Collector-Emitter Voltage | V _{CEO} | -45 | -60 | -80 | V |
| Emitter-Base Voltage | V _{EBO} | | -5 | | |
| Continuous Collector Current | Ic | -1 | | | A mA |
| Peak Pulse Collector Current | I _{CM} | -2 | | | |
| Continuous Base Current | I _B | -100 | | | |
| Peak Pulse Base Current | I _{BM} | -200 | | | |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|--|----------------------------------|-------------------|------|------|
| Power Dissipation | (Note 6) | P_{D} | 2 | W |
| Thermal Resistance, Junction to Ambient | (Note 6) | $R_{\theta JA}$ | 62 | °C/W |
| Thermal Resistance, Junction to Leads (Note 7) | | R ₀ JL | 19.4 | °C/W |
| Operating and Storage Temperature Range | T _{J,} T _{STG} | -65 to +150 | °C | |

ESD Ratings (Note 8)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

Notes:

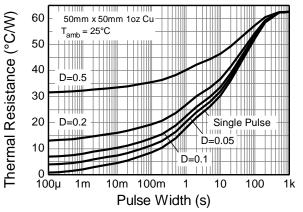
^{6.} For a device mounted with the collector lead on 50mm x 50mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

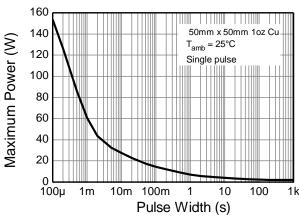
^{7.} Thermal resistance from junction to solder-point (at the end of the collector lead).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



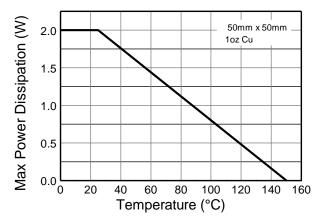
Thermal Characteristics and Derating Information





Transient Thermal Impedance

Pulse Power Dissipation



Derating Curve

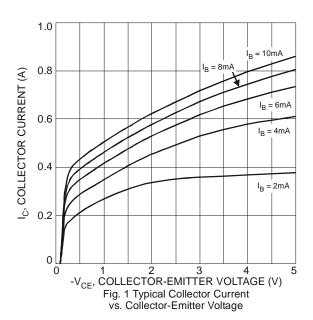


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Min | Тур | Max | Unit | Test Condition |
|---|-------------------------|----------------------|--------------------|-------------|---------------|------------------|---|
| Collector-Base Breakdown Voltage | BCP51 BCP52 BCP53 | BV _{CBO} | -45 -60 -100 | | | > | I _C = -100μA |
| Collector-Emitter Breakdown Voltage (Note 9) | BCP51 BCP52 BCP53 | BV _{CEO} | -45 -60 -80 | _ | _ | > | I _C = -10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -5 | _ | _ | V | $I_E = -10\mu A$ | |
| Collector Cut-Off Current | | I _{CBO} | _ | _ | -0.1 -20 | μΑ | V _{CB} = -30V V _{CB} = -30V, T _A = +150°C |
| Emitter Cut-Off Current | | I _{EBO} | _ | _ | -20 | nA | V _{EB} = -4V |
| Static Forward Current Transfer Ratio (Note 9) | All Versions | h _{FE} | 25 40 25 | _ _ _ | _ 250 _ | | $I_C = -5mA$, $V_{CE} = -2V$ $I_C = -150mA$, $V_{CE} = -2V$ $I_C = -500mA$, $V_{CE} = -2V$ |
| , | 10 gain grp | | 63 | _ | 160 | | I _C = -150mA, V _{CE} = -2V |
| | 16 gain grp |] | 100 | _ | 250 | | I _C = -150mA, V _{CE} = -2V |
| Collector-Emitter Saturation Voltage (Note 9) | | V _{CE(sat)} | _ | _ | -0.5 | V | $I_C = -500 \text{mA}, I_B = -50 \text{mA}$ |
| Base-Emitter Turn-On Voltage (Note 9) | | V _{BE(on)} | _ | _ | -1.0 | V | $I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$ |
| Transition Frequency | | f⊤ | 150 | _ | _ | MHz | $I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$ f = 100MHz |
| Output Capacitance | | Cobo | _ | _ | 25 | pF | $V_{CB} = -10V$, $f = 1MHz$ |

Note:

9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



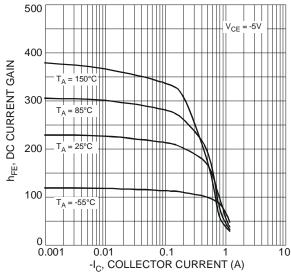


Fig. 2 Typical DC Current Gain vs. Collector Current



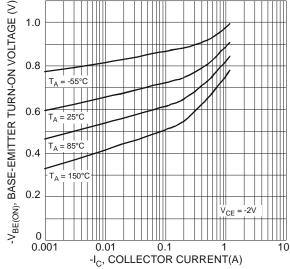


Fig 3 Typical Base-Emitter Turn-On Voltage vs. Collector Current

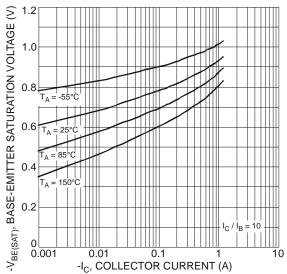
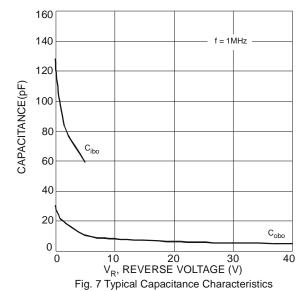


Fig. 5 Typical Base-Emitter Saturation Voltage vs. Collector Current



-I_C, COLLECTOR CURRENT (A)
Fig. 4 Typical Collector-Emitter Saturation Voltage
vs. Collector Current

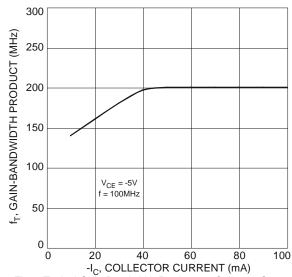
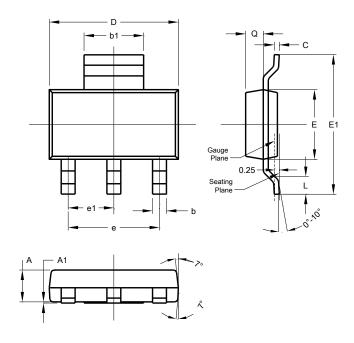


Fig. 6 Typical Gain-Bandwidth Product vs. Collector Current



Package Outline Dimensions

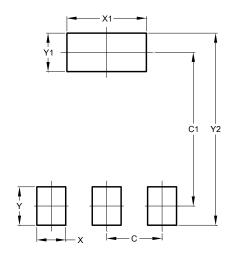
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



| SOT223 | | | | | | |
|----------------------|-------|------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 1.55 | 1.65 | 1.60 | | | |
| A1 | 0.010 | 0.15 | 0.05 | | | |
| b | 0.60 | 0.80 | 0.70 | | | |
| b1 | 2.90 | 3.10 | 3.00 | | | |
| С | 0.20 | 0.30 | 0.25 | | | |
| D | 6.45 | 6.55 | 6.50 | | | |
| Е | 3.45 | 3.55 | 3.50 | | | |
| E1 | 6.90 | 7.10 | 7.00 | | | |
| е | - | - | 4.60 | | | |
| e1 | - | - | 2.30 | | | |
| L | 0.85 | 1.05 | 0.95 | | | |
| ø | 0.84 | 0.94 | 0.89 | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.30 |
| C1 | 6.40 |
| Х | 1.20 |
| X1 | 3.30 |
| Y | 1.60 |
| Y1 | 1.60 |
| Y2 | 8.00 |



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